

GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION.

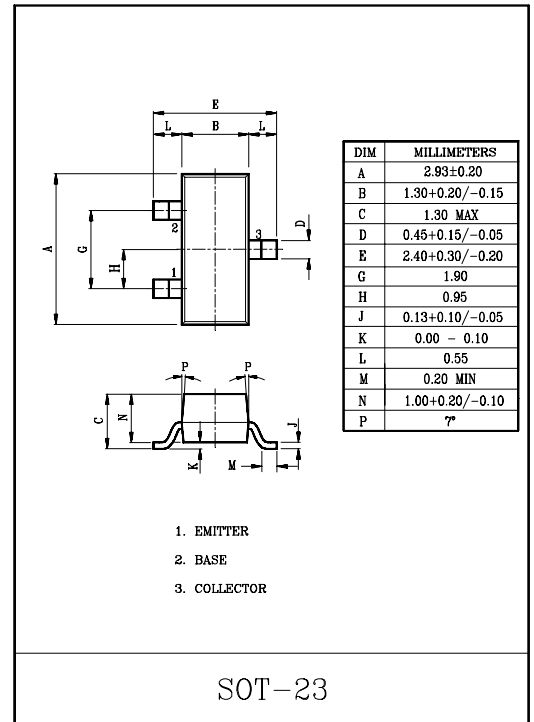
FEATURES

- Low Leakage Current
: $I_{CEX} = -50nA(\text{Max.})$, $I_{BL} = -50nA(\text{Max.})$
@ $V_{CE} = -30V$, $V_{EB} = -3V$.
- Excellent DC Current Gain Linearity.
- Low Saturation Voltage
: $V_{CE(sat)} = -0.4V(\text{Max.})$ @ $I_C = -50mA$, $I_B = -5mA$.
- Low Collector Output Capacitance
: $C_{ob} = 4.5pF(\text{Max.})$ @ $V_{CB} = -5V$.
- Complementary to 2N3904S.

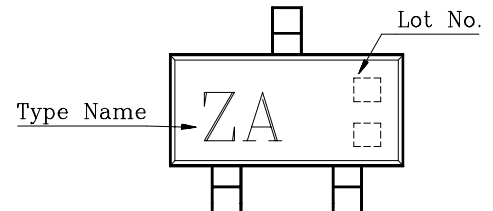
MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-200	mA
Base Current	I_B	-50	mA
Collector Power Dissipation (Ta=25°C)	P_C *	350	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

Note : * Package Mounted On 99.5% Alumina 10x8x0.6mm



Marking



2N3906S

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT			
Collector Cut-off Current	I_{CEX}	$V_{CE}=-30V, V_{EB}=-3V$	-	-	-50	nA			
Base Cut-off Current	I_{BL}	$V_{CE}=-30V, V_{EB}=-3V$	-	-	-50	nA			
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-10\mu A, I_E=0$	-40	-	-	V			
Collector-Emitter Breakdown Voltage *	$V_{(BR)CEO}$	$I_C=-1mA, I_B=0$	-40	-	-	V			
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-10\mu A, I_C=0$	-5.0	-	-	V			
DC Current Gain *	$h_{FE(1)}$	$V_{CE}=-1V, I_C=-0.1mA$	60	-	-				
	$h_{FE(2)}$	$V_{CE}=-1V, I_C=-1mA$	80	-	-				
	$h_{FE(3)}$	$V_{CE}=-1V, I_C=-10mA$	100	-	300				
	$h_{FE(4)}$	$V_{CE}=-1V, I_C=-50mA$	60	-	-				
	$h_{FE(5)}$	$V_{CE}=-1V, I_C=-100mA$	30	-	-				
Collector-Emitter Saturation Voltage *	$V_{CE(sat)1}$	$I_C=-10mA, I_B=-1mA$	-	-	-0.25	V			
	$V_{CE(sat)2}$	$I_C=-50mA, I_B=-5mA$	-	-	-0.4				
Base-Emitter Saturation Voltage *	$V_{BE(sat)1}$	$I_C=-10mA, I_B=-1mA$	-0.65	-	-0.85	V			
	$V_{BE(sat)2}$	$I_C=-50mA, I_B=-5mA$	-	-	-0.95				
Transition Frequency	f_T	$V_{CE}=-20V, I_C=-10mA, f=100MHz$	250	-	-	MHz			
Collector Output Capacitance	C_{ob}	$V_{CB}=-5V, I_E=0, f=1MHz$	-	-	4.5	pF			
Input Capacitance	C_{ib}	$V_{BE}=-0.5V, I_C=0, f=1MHz$	-	-	10	pF			
Input Impedance	h_{ie}	$V_{CE}=-10V, I_C=-1mA, f=1kHz$	2.0	-	12	k Ω			
Voltage Feedback Ratio	h_{re}		1.0	-	10	$\times 10^{-4}$			
Small-Signal Current Gain	h_{fe}		100	-	400				
Collector Output Admittance	h_{oe}		3.0	-	60	μS			
Noise Figure	NF		$V_{CE}=-5V, I_C=-0.1mA$ $R_g=1k\Omega, f=10Hz \sim 15.7kHz$	-	-	4.0	dB		
Switching Time	Delay Time	t_d				-	-	35	nS
	Rise Time	t_r				-	-	35	
	Storage Time	t_{stg}				-	-	225	
	Fall Time	t_f				-	-	75	

Note : *Pulse Test : Pulse Width $\leq 300\mu S$, Duty Cycle $\leq 2.0\%$

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